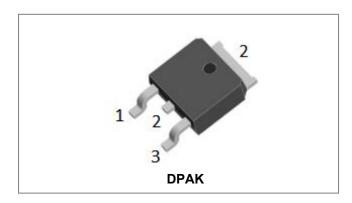






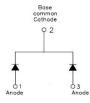
MBRD10200CT SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Maximum Ratings:

Characteristics	Symbol	Condition Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =105°C, rectangular wave form	5(peg leg) 10(peg device)	Α
Peak One Cycle Non-Repetitive Surge Current(peg leg)	I _{FSM}	8.3 ms, half Sine pulse	128	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.85	0.90	V
(per leg) *	V _{F2}	@ 5A, Pulse, T _J = 125 °C	0.70	0.74	V
Reverse Current (per leg) *	I _{R1}	I_{R1} @V _R = rated V _R , T _J = 25 °C		1	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.05	25	mA
Junction Capacitance(per leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	90	150	pF
Voltage Rate of Change	dv/dt	/dt		10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

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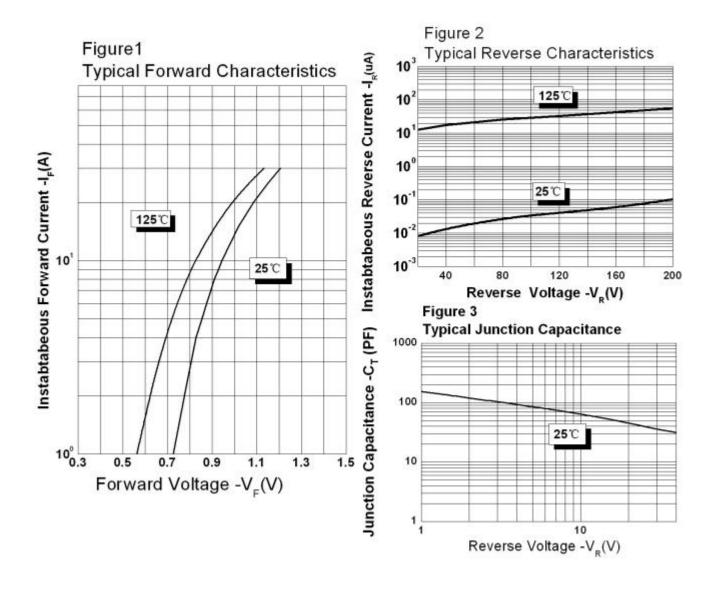




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to + 150	°C
Typical Thermal Resistance Junction to	D		3.5(per leg)	°C/W
Case	$R_{\theta JC}$	-	2(per package)	-0/00
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

Ratings and Characteristics Curves



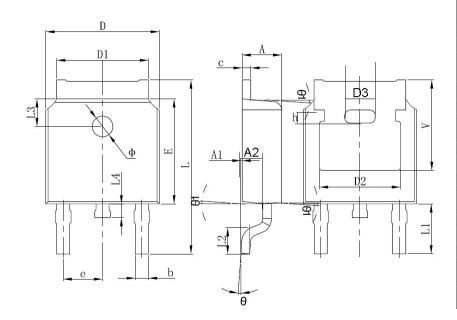
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Mechanical Dimensions DPAK



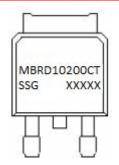
CVMDOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.087	0.094	
A1	0.00	0.127	0.000	0.005	
b	0.66	0.86	0.026	0.034	
С	0.46	0.60	0.018	0.024	
D	6.50	6.70	0.256	0.264	
D1	5.13	5.46	0.202	0.215	
D2	4.83	REF.	0.190 REF.		
Е	6.00	6.20	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.70	10.40	0.381	0.409	
L1	2.90 REF.		0.144 REF.		
L2	1.40	1.70	0.055	0.067	
L3	1.60 REF.		0.063 REF.		
L4	0.60	1.00	0.024	0.039	
Ф	1.10	1.30	0.043	0.051	
Θ	0°	8°	0°	8°	
h	0.00	0.30	0.000	0.012	
V	5.35 REF.		0.211 REF.		

Ordering Information

Device	Package	Shipping	
MBRD10200CT	DPAK (Pb-Free)	2500pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel Packaging specification.

Marking Diagram



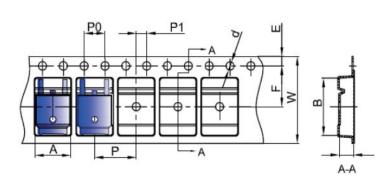
Where XXXXX is YYWWL

MBR = Device Type
D = Package type
10 = Forward Current (10A)
200 = Reverse Voltage (200V)
CT = Configuration

SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DPAK



SYMBOL	Millimeters		
STWIDOL	Min.	Max.	
Α	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Ф1.45	Ф1.65	
E	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

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